

Title (en)

METHOD FOR ENCAPSULATING INTEGRATED CIRCUITS.

Title (de)

VERKAPSELUNGSVERFAHREN FÜR INTEGRIERTE SCHALTUNGEN.

Title (fr)

PROCEDE D'ENCAPSULATION DE CIRCUITS INTEGRES.

Publication

**EP 0264416 A1 19880427 (FR)**

Application

**EP 87902560 A 19870429**

Priority

FR 8606333 A 19860430

Abstract (en)

[origin: WO8706763A1] For encapsulating integrated circuits mounted on a continuous dielectric strip (10) (surface-mounted circuits), it is proposed to cast by transfer a thermo-setting resin around the circuits carried by the strip, the injection of resin occurring outside the mating plane of the mould, contrary to what is usually done in this field. The protection of circuits is improved while preserving the testability on the strip.

Abstract (fr)

Pour l'encapsulation des circuits intégrés montés sur bande continue diélectrique (10) (circuits montables en surface), on propose de mouler par transfert une résine thermodurcissable autour des circuits portés par la bande, l'injection de résine se faisant en dehors du plan de joint du moule contrairement à ce qui est habituel dans ce domaine. On améliore la protection des circuits en conservant la testabilité sur bande.

IPC 1-7

**H01L 21/56**

IPC 8 full level

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CPC (source: EP KR US)

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C-Set (source: EP US)

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See references of WO 8706763A1

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DOCDB simple family (application)

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